

A Modified Equivalent-Network Model for the Liquid-Level Sensors Operating in Trapped-Energy Vibration Modes

エバネセント波を用いた液面レベルセンサの等価回路表現 —伝搬定数複素化の試み—

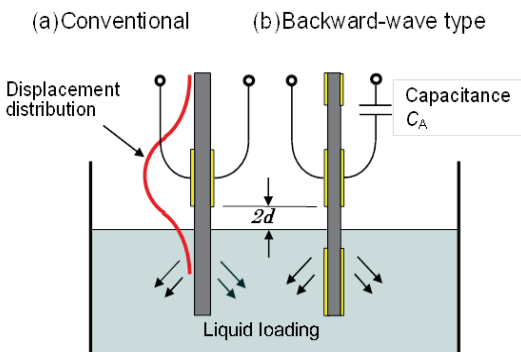
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1. Introduction

Novel sensors for detecting a small-scale variation in liquid level that employ a trapped-energy mode of conventional and/or backward-wave type have been studied by the authors' group¹⁻¹⁰⁾. The sensors have been modeled⁶⁻¹⁰⁾ by a distributed-constant electric network representing the propagation of thickness-vibration modes^{11,12)}. In these models the effect of liquid loading is expressed by putting the characteristic impedance of the corresponding part to be complex¹⁰⁾. In this paper, an improved treatment is presented for the transmission-line model that employs a complex wavenumber for the liquid-immersed region, and some results of simulation are shown.

2. Geometry of the Sensors Utilizing Trapped-Energy Vibration Modes

The sensor configurations utilizing trapped-energy vibration modes are shown in Fig. 1 for a conventional type, (a), and a backward-wave type, (b). By dipping the evanescent-wave region of the resonators in a liquid, a depth-dependent variation in the electric admittance Y will occur at the resonance. In the case of backward-wave-type energy trapping^{12),13)}, the surrounding region of the piezoelectric plate is electroded and short-circuited as presented in Fig. 1(b). An additional capacitance C_A is connected in series with the central excitation electrodes to ensure energy trapping.



3. Equivalent-Network Modeling and Results of Analyses

The equivalent network model for the sensor utilizing the conventional trapped-energy mode is rather simple⁶⁾. In the backward-wave-type trapped-energy vibrator¹⁰⁾, however, there exists a non-electroded gap region between the central and the surrounding electrodes. The wavenumber there can be real even when the energy-trapping works. Therefore, the wavenumber and the characteristic impedance of this region should be complex to take the leakage loss into consideration when this region is immersed in a liquid.

Figure 2 shows the equivalent network model for the sensor utilizing the backward-wave-type energy trapping^{9),10)}. Here, the liquid surface may be either on the gap or on the outer electrodes. In the sensing side, two transmission lines representing the unelectroded gap of the length $2l'$ are connected serially to the network elements corresponding to the central excitation electrode part. One is the transmission line representing the out-of-liquid portion of length $2d$, where the wave number is γ' and the characteristic impedance is Z_0' . The other is the line of length $2l''$ ($=2l'-2d$) representing the portion in the liquid. The wavenumber and the characteristic impedance in

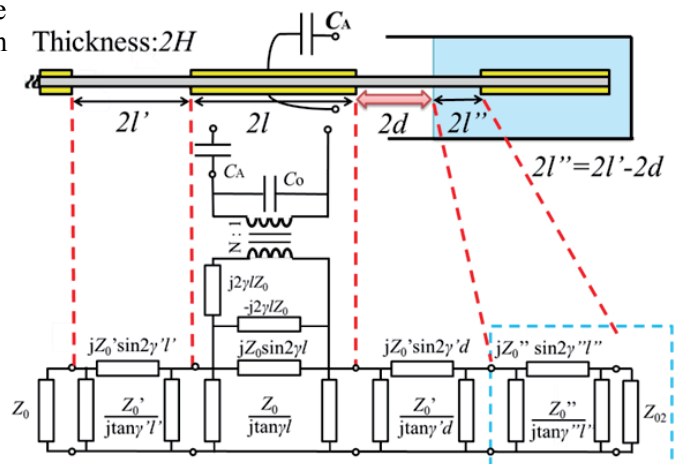


Fig.1 Liquid-level sensing by trapped-energy vibrators. Fig.2 Equivalent network for the sensor of backward-wave energy trapping.

this part are complex values and expressed as γ'' and Z_0'' , respectively. Here, γ'' is expressed by introducing a factor m as:

$$\gamma'' = \gamma'(1 - jm)$$

The outermost metallized region is supposed to have an infinite length and is therefore expressed by the corresponding characteristic impedance Z_{02} .

A thickness-poled PbTiO_3 plate is assumed as the backward-wave-type trapped-energy resonator model. The ratio of the central electrode width $2l$ to the plate thickness $2H$ is supposed to be 4.0 and the normalized gap width l'/H is supposed to be 0.5 or 1.0. The ratio of the damped capacitance C_0 to the series capacitance C_A is 1.0. A small amount of resistance is added at the electric port to take the material loss into account.

The variations in the peak value of the electric conductance G with the liquid level at the resonance frequency are shown in Fig. 3. The normalized gap width l'/H is 0.5 in Fig. 3(a) and 1.0 in Fig. 3(b). The vertical axis is normalized to the value for liquid-free condition. Here, the factor m is varied from 1×10^{-3} to 2×10^{-4} .

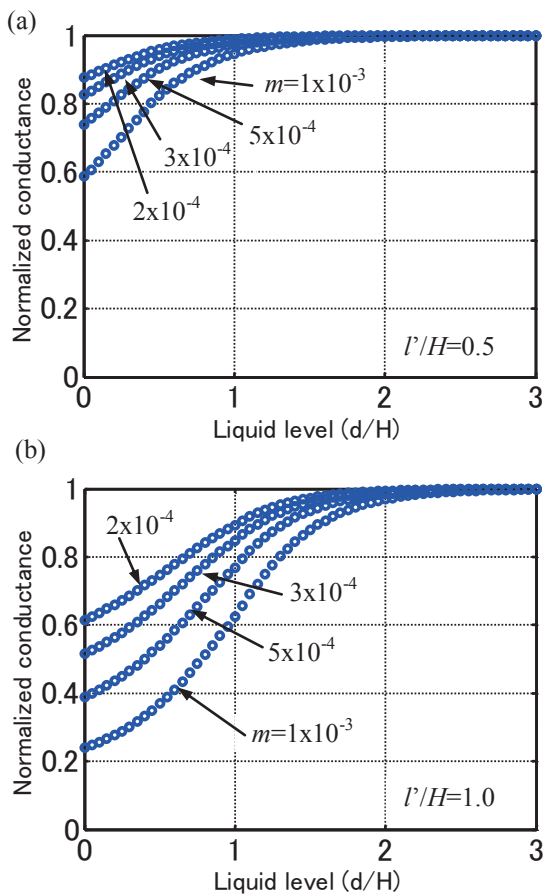


Fig. 3 Variation in G with the liquid level at resonance ($l'/H=0.5$ for (a) and 1.0 for (b)).

It is noted that continuous decrease in the electric conductance level is obtained as the liquid surface approaches to the central electrodes (d/H reduces to 0).

4. Conclusions

An improved treatment has been presented for the equivalent-network model of the liquid-level sensor proposed by the authors. Variation of the electric conductance on the liquid level presented in the former studies¹⁾⁻⁵⁾ is well simulated. However, further investigation is required to clarify the relationship between the elastic property of the liquid and the factor m .

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